Switching (-20V, -3.0A)

RTR030P02

Features

- 1) Low On-resistance.
- 2) Built-in G-S Protection Diode.
- 3) Small and Surface Mount Package (TSMT3).

Application

Power switching, DC / DC converter.

●Structure

Silicon P-channel MOS FET

Packaging specifications

| | Package | Taping |
|-----------|------------------------------|--------|
| Type | Code | TL |
| | Basic ordering unit (pieces) | 3000 |
| RTR030P02 | | 0 |

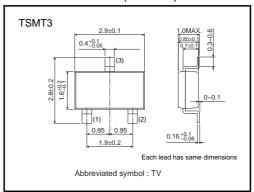
● Absolute maximum ratings (Ta=25°C)

| Parameter | | Symbol | Limits | Unit | |
|------------------------------|------------|-------------------|------------|------|--|
| Drain-source voltage | | V_{DSS} | -20 | V | |
| Gate-source voltage | | Vgss | ±12 | V | |
| Drain current | Continuous | ID | ±3.0 | Α | |
| | Pulsed | IDP *1 | ±12 | Α | |
| Source current | Continuous | Is | -0.8 | Α | |
| (Body diode) | Pulsed | Isp *1 | -3.2 | Α | |
| Total power dissipation | | P _D *2 | 1.0 | W | |
| Channel temperature | | Tch | 150 | °C | |
| Range of Storage temperature | | Tstg | -55 to 150 | °C | |

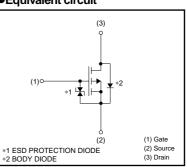
- *1 Pw≤10μs, Duty cycle≤1% *2 Mounted on a ceramic board
- ●Thermal resistance (Ta=25°C)

| Parameter | Symbol | Limits | Unit |
|--------------------|------------|--------|--------|
| Channel to ambient | Rth (ch-A) | 125 | °C / W |

●External dimensions (Unit : mm)



●Equivalent circuit



●Electrical characteristics (Ta=25°C)

| Parameter | Symbol | Min. | Тур. | Max. | Unit | Conditions | |
|-----------------------------------------|-----------------------|------|------|------|------|-------------------------------------------------------------------------|--|
| Gate-source leakage | Igss | _ | _ | ±10 | μΑ | Vgs=±12V, Vps=0V | |
| Drain-source breakdown voltage | V _{(BR) DSS} | -20 | _ | _ | V | I _D = -1mA, V _G S=0V | |
| Zero gate voltage drain current | IDSS | _ | _ | -1 | μΑ | V _{DS} = -20V, V _{GS} =0V | |
| Gate threshold voltage | V _{GS (th)} | -0.7 | _ | -2.0 | V | V_{DS} = -10V, I_D = -1mA | |
| Static drain-source on-state resistance | R _{DS} (on)* | _ | 55 | 75 | mΩ | I _D = -3.0A, V _G S= -4.5V | |
| | | _ | 60 | 85 | mΩ | I _D = -3.0A, V _G S= -4.0V | |
| | | _ | 90 | 125 | mΩ | I _D = -1.5A, V _G S= -2.5V | |
| Forward transfer admittance | Y _{fs} * | 2.5 | - | _ | S | V _{DS} = -10V, I _D = -1.5A | |
| Input capacitance | Ciss | _ | 840 | _ | pF | Vps= -10V | |
| Output capacitance | Coss | - | 140 | _ | pF | V _{GS} =0V | |
| Reverse transfer capacitance | Crss | _ | 100 | _ | pF | f=1MHz | |
| Turn-on delay time | t d (on) * | _ | 12 | _ | ns | I _D = -1.5A | |
| Rise time | tr * | _ | 20 | _ | ns | $V_{DD} = -15V$ $V_{GS} = -4.5V$ $R_{L} = 10\Omega$ $R_{GS} = 10\Omega$ | |
| Turn-off delay time | td (off) * | _ | 50 | _ | ns | | |
| Fall time | t _f * | _ | 20 | _ | ns | | |
| Total gate charge | Qg | - | 9.3 | _ | nC | V _{DD} ≒-15V | |
| Gate-source charge | Qgs | _ | 1.6 | _ | nC | Vgs=-4.5V | |
| Gate-drain charge | Qgd | - | 2.6 | _ | nC | ID=-3.0A | |

*Pulsed

Body diode characteristics (source-drain characteristics)

Electrical characteristic curves

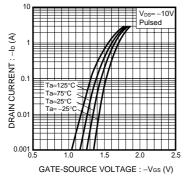


Fig.1 Typical Transfer Characteristics

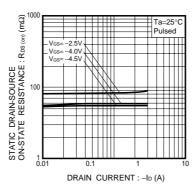


Fig.2 Static Drain-Source On-State Resistance vs. Drain Current

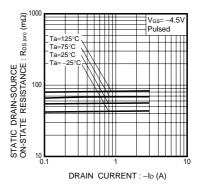


Fig.3 Static Drain-Source On-State Resistance vs. Drain Current

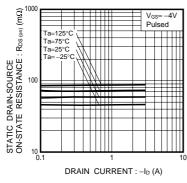


Fig.4 Static Drain-Source On-State Resistance vs. Drain Current

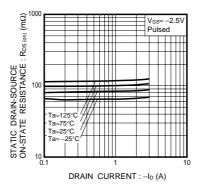


Fig.5 Static Drain-Source On-State Resistance vs. Drain Current

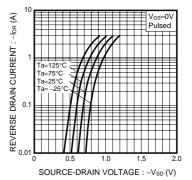


Fig.6 Reverse Drain Current vs.Source-Drain Voltage

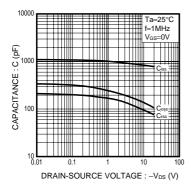


Fig.7 Typical Capacitance vs. Drain-Source Voltage

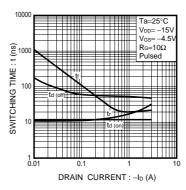


Fig.8 Switching Characteristics

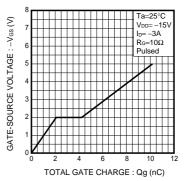


Fig.9 Dynamic Input Characteristics

●Measurement circuits

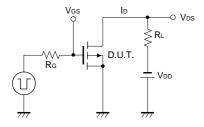


Fig.10 Switching Time Test Circuit

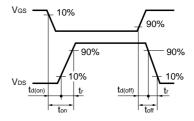


Fig.11 Switching Time Waveforms

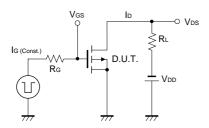


Fig.12 Gate Charge Test Circuit

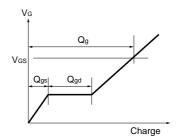


Fig.13 Gate Charge Waveform

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